Dual low-ohmic single-pole single-throw analog switch

Rev. 5 - 8 February 2013

Product data sheet

General description 1.

The NX3L2T384 is a dual low-ohmic single-pole single-throw analog switch. Each switch has two input/output terminals (nY and nZ) and an active LOW enable input (nE). When pin nE is HIGH, the analog switch is turned off.

Schmitt trigger action at the enable input (nE) makes the circuit tolerant to slower input rise and fall times. A low input voltage threshold allows pin nE to be driven by lower level logic signals without a significant increase in supply current I_{CC} . This makes it possible for the NX3L2T384 to switch 4.3 V signals with a 1.8 V digital controller, eliminating the need for logic level translation.

The NX3L2T384 allows signals with amplitude up to V_{CC} to be transmitted from nY to nZ; or from nZ to nY. Its low ON resistance (0.5 Ω) and flatness (0.13 Ω) ensures minimal attenuation and distortion of transmitted signals.

Features and benefits 2.

- Wide supply voltage range from 1.4 V to 4.3 V
- Very low ON resistance (peak):
 - 1.6 Ω (typical) at V_{CC} = 1.4 V
 - 1.0 Ω (typical) at V_{CC} = 1.65 V
 - 0.55 Ω (typical) at V_{CC} = 2.3 V
 - 0.50 Ω (typical) at V_{CC} = 2.7 V
 - 0.50 Ω (typical) at V_{CC} = 4.3 V
- High noise immunity
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 7500 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM AEC-Q100-011 revision B exceeds 1000 V
 - IEC61000-4-2 contact discharge exceeds 4000 V for switch ports
- CMOS low-power consumption
- Latch-up performance exceeds 100 mA per JESD 78B Class II Level A
- 1.8 V control logic at V_{CC} = 3.6 V
- Control input accepts voltages above supply voltage
- Very low supply current, even when input is below V_{CC}
- High current handling capability (350 mA continuous current under 3.3 V supply)
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C



Dual low-ohmic single-pole single-throw analog switch

Applications 3.

- Cell phone
- PDA
- Portable media player

Ordering information 4.

Table 1. **Ordering information**

| Type number | Package | | | | | | | |
|-------------|-------------------|-------|---|----------|--|--|--|--|
| | Temperature range | Name | Description | Version | | | | |
| NX3L2T384GT | -40 °C to +125 °C | XSON8 | plastic extremely thin small outline package; no leads; 8 terminals; body 1 \times 1.95 \times 0.5 mm | SOT833-1 | | | | |
| NX3L2T384GD | –40 °C to +125 °C | XSON8 | plastic extremely thin small outline package; no leads; 8 terminals; body $3 \times 2 \times 0.5$ mm | SOT996-2 | | | | |
| NX3L2T384GM | –40 °C to +125 °C | XQFN8 | plastic, extremely thin quad flat package; no leads; 8 terminals; body $1.6 \times 1.6 \times 0.5$ mm | SOT902-2 | | | | |

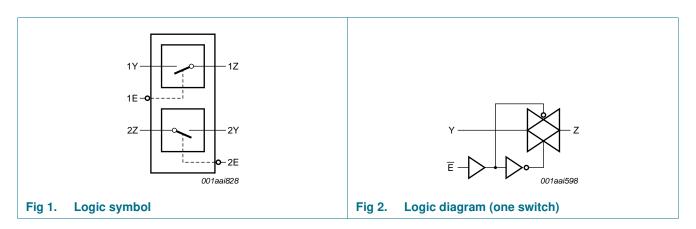
Marking 5.

Marking codes^[1] Table 2.

| Type number | Marking code |
|-------------|--------------|
| NX3L2T384GT | M84 |
| NX3L2T384GD | M84 |
| NX3L2T384GM | M84 |

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

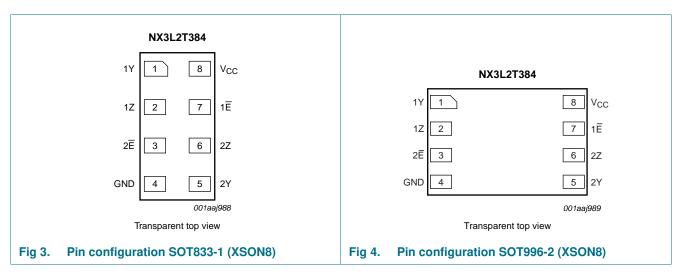
Functional diagram 6.

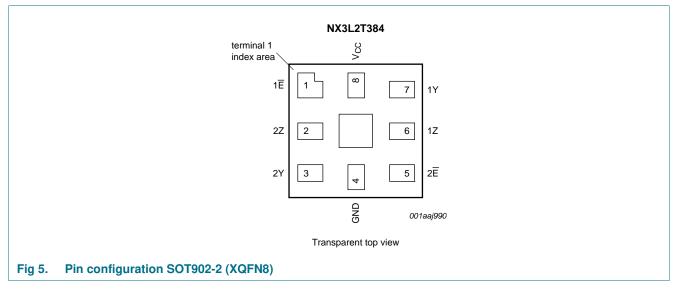


Dual low-ohmic single-pole single-throw analog switch

7. Pinning information

7.1 Pinning





7.2 Pin description

| Table 3. | Pin description | | | | | |
|----------|-----------------------|----------|--|--|--|--|
| Symbol | Pin | | | | | |
| | SOT833-1 and SOT996-2 | SOT902-2 | | | | |

| | SO1833-1 and SO1996-2 | 501902-2 | |
|-----------------|-----------------------|----------|-----------------------------|
| 1Y, 2Y | 1, 5 | 7, 3 | independent input or output |
| 1Z, 2Z | 2, 6 | 6, 2 | independent input or output |
| GND | 4 | 4 | ground (0 V) |
| 1Ē, 2Ē | 7, 3 | 1, 5 | enable input (active HIGH) |
| V _{CC} | 8 | 8 | supply voltage |
| | | | |

Description

NX3L2T384 Product data sheet Dual low-ohmic single-pole single-throw analog switch

8. Functional description

| Table 4. | Function table ^[1] |
|----------|-------------------------------|
|----------|-------------------------------|

| Input nE | Switch |
|----------|-----------|
| L | ON-state |
| Н | OFF-state |

[1] H = HIGH voltage level; L = LOW voltage level.

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------|--|-----------------|----------------|------|
| V _{CC} | supply voltage | | -0.5 | +4.6 | V |
| VI | input voltage | enable input nE | <u>[1]</u> –0.5 | +4.6 | V |
| V _{SW} | switch voltage | | [2] -0.5 | $V_{CC} + 0.5$ | V |
| I _{IK} | input clamping current | V _I < -0.5 V | -50 | - | mA |
| I _{SK} | switch clamping current | $V_{\rm I} < -0.5$ V or $V_{\rm I} > V_{\rm CC}$ + 0.5 V | - | ±50 | mA |
| I _{SW} | switch current | V_{SW} > -0.5 V or V_{SW} < V_{CC} + 0.5 V; source or sink current | - | ±350 | mA |
| | | V_{SW} > -0.5 V or V_{SW} < V_{CC} + 0.5 V; pulsed at 1 ms duration, < 10 % duty cycle; peak current | - | ±500 | mA |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| P _{tot} | total power dissipation | $T_{amb} = -40 \text{ °C to } +125 \text{ °C}$ | <u>[3]</u> _ | 250 | mW |
| | | | | | |

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed but may not exceed 4.6 V.

[3] For XSON8 and XQFN8 packages: above 118 °C the value of Ptot derates linearly with 7.8 mW/K.

10. Recommended operating conditions

Table 6. Recommended operating conditions

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|-------------------------------------|--|-------|-----|-----------------|------|
| V_{CC} | supply voltage | | 1.4 | - | 4.3 | V |
| VI | input voltage | enable input nE | 0 | - | 4.3 | V |
| V_{SW} | switch voltage | | [1] 0 | - | V _{CC} | V |
| T _{amb} | ambient temperature | | -40 | - | +125 | °C |
| $\Delta t / \Delta V$ | input transition rise and fall rate | $V_{CC} = 1.4 \text{ V} \text{ to } 4.3 \text{ V}$ | [2] - | - | 200 | ns/V |

[1] To avoid sinking GND current from terminal nZ when switch current flows in terminal nY, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal nZ, no GND current will flow from terminal nY. In this case, there is no limit for the voltage drop across the switch.

[2] Applies to control signal levels.

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Dual low-ohmic single-pole single-throw analog switch

11. Static characteristics

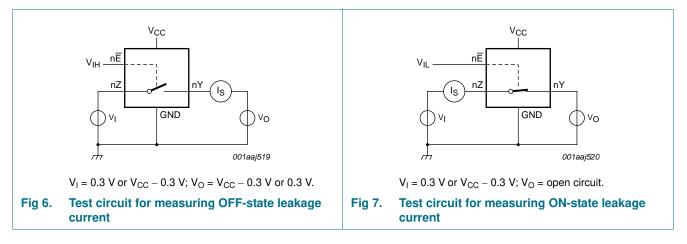
Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

| Symbol | Parameter | Conditions | Ta | _{mb} = 25 | °C | T_{amb} = -40 °C to +125 °C | | | Unit |
|---------------------|--------------------------|--|-----|--------------------|------|-------------------------------|----------------|-----------------|------|
| | | | Min | Тур | Max | Min | Max (85 °C) | Max (125 °C) | |
| V _{IH} | HIGH-level | V _{CC} = 1.4 V to 1.6 V | 0.9 | - | - | 0.9 | - | - | V |
| | input voltage | $V_{CC} = 1.65 \text{ V} \text{ to } 1.95 \text{ V}$ | 0.9 | - | - | 0.9 | - | - | V |
| | | V_{CC} = 2.3 V to 2.7 V | 1.1 | - | - | 1.1 | - | - | V |
| | | $V_{CC} = 2.7 \text{ V} \text{ to } 3.6 \text{ V}$ | 1.3 | - | - | 1.3 | - | - | V |
| | | $V_{CC} = 3.6 \text{ V} \text{ to } 4.3 \text{ V}$ | 1.4 | - | - | 1.4 | - | - | V |
| V _{IL} | LOW-level | $V_{CC} = 1.4 \text{ V}$ to 1.6 V | - | - | 0.3 | - | 0.3 | 0.3 | V |
| | input voltage | V _{CC} = 1.65 V to 1.95 V | - | - | 0.4 | - | 0.4 | 0.3 | V |
| | | $V_{CC} = 2.3 \text{ V} \text{ to } 2.7 \text{ V}$ | - | - | 0.4 | - | 0.4 | 0.4 | V |
| | | $V_{CC} = 2.7 \text{ V} \text{ to } 3.6 \text{ V}$ | - | - | 0.5 | - | 0.5 | 0.5 | V |
| | | $V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$ | - | - | 0.6 | - | 0.6 | 0.6 | V |
| l _l | input leakage current | enable input $n\overline{E}$; V _I = GND to 4.3 V; V _{CC} = 1.4 V to 4.3 V | - | - | - | - | ±0.5 | ±1 | μA |
| I _{S(OFF)} | OFF-state | nY port; see Figure 6 | | | | | | | |
| | leakage | $V_{CC} = 1.4 \text{ V} \text{ to } 3.6 \text{ V}$ | - | - | ±5 | - | ±50 | ±500 | nA |
| | current | $V_{CC} = 3.6 V \text{ to } 4.3 V$ | - | - | ±10 | - | ±50 | ±500 | nA |
| I _{S(ON)} | ON-state | nZ port; see Figure 7 | | | | | | | |
| | leakage | $V_{CC} = 1.4 \text{ V} \text{ to } 3.6 \text{ V}$ | - | - | ±5 | - | ±50 | ±500 | nA |
| | current | $V_{CC} = 3.6 \text{ V} \text{ to } 4.3 \text{ V}$ | - | - | ±10 | - | ±50 | ±500 | nA |
| I _{CC} | supply current | $V_I = V_{CC}$ or GND; $V_{SW} = GND$ or V_{CC} | | | | | | | |
| | | $V_{CC} = 3.6 V$ | - | - | 100 | - | 690 | 6000 | nA |
| | | $V_{CC} = 4.3 V$ | - | - | 150 | - | 800 | 7000 | nA |
| ΔI_{CC} | additional | $V_{SW} = GND \text{ or } V_{CC}$ | | | | | | | |
| | supply current | $V_1 = 2.6 \text{ V}; V_{CC} = 4.3 \text{ V}$ | - | 2.0 | 4.0 | - | 7 | 7 | μA |
| | | $V_{I} = 2.6 \text{ V}; V_{CC} = 3.6 \text{ V}$ | - | 0.35 | 0.7 | - | 1 | 1 | μA |
| | | $V_{I} = 1.8 V; V_{CC} = 4.3 V$ | - | 7.0 | 10.0 | - | 15 | 15 | μA |
| | | $V_{I} = 1.8 V; V_{CC} = 3.6 V$ | - | 2.5 | 4.0 | - | 5 | 5 | μA |
| | | $V_{I} = 1.8 \text{ V}; V_{CC} = 2.5 \text{ V}$ | - | 50 | 200 | - | 300 | 500 | nA |
| CI | input capacitance | | - | 1.0 | - | - | - | - | pF |
| $C_{S(OFF)}$ | OFF-state capacitance | | - | 35 | - | - | - | - | pF |
| C _{S(ON)} | ON-state capacitance | | - | 110 | - | - | - | - | pF |

Dual low-ohmic single-pole single-throw analog switch

11.1 Test circuits



11.2 ON resistance

Table 8.ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see Figure 9 to Figure 15.

| Symbol | Parameter | Conditions | | T_{amb} = -40 °C to +85 °C | | | T_{amb} = -40 ° | Unit | |
|---|--|--|------------|------------------------------|----------------------|-------|-------------------|------|---|
| | | | | Min | Typ <mark>[1]</mark> | Max | Min | Max | |
| R _{ON(peak)} | ON resistance (peak) | $V_{I} = GND \text{ to } V_{CC};$ $I_{SW} = 100 \text{ mA};$ see <u>Figure 8</u> | | | | | | | |
| | | V _{CC} = 1.4 V | | - | 1.6 | 3.7 | - | 4.1 | Ω |
| | | V _{CC} = 1.65 V | | - | 1.0 | 1.6 | - | 1.7 | Ω |
| | | $V_{CC} = 2.3 V$ | | - | 0.55 | 0.8 | - | 0.9 | Ω |
| | | $V_{CC} = 2.7 V$ | | - | 0.5 | 0.75 | - | 0.9 | Ω |
| | | $V_{CC} = 4.3 V$ | | - | 0.5 | 0.75 | - | 0.9 | Ω |
| ΔR _{ON} ON resistance mismatch between | $V_I = GND$ to V_{CC} ; $I_{SW} = 100 \text{ mA}$ | [2] | | | | | | | |
| | channels | $V_{CC} = 1.4 V$ | | - | 0.04 | 0.3 | - | 0.3 | Ω |
| | | V _{CC} = 1.65 V | | - | 0.04 | 0.2 | - | 0.3 | Ω |
| | | $V_{CC} = 2.3 V$ | | - | 0.02 | 0.08 | - | 0.1 | Ω |
| | | $V_{CC} = 2.7 V$ | | - | 0.02 | 0.075 | - | 0.1 | Ω |
| | | $V_{CC} = 4.3 V$ | | - | 0.02 | 0.075 | - | 0.1 | Ω |
| $R_{ON(flat)}$ | ON resistance (flatness) | $V_I = GND$ to V_{CC} ; $I_{SW} = 100 \text{ mA}$ | <u>[3]</u> | | | | | | |
| | | $V_{CC} = 1.4 V$ | | - | 1.0 | 3.3 | - | 3.6 | Ω |
| | | $V_{CC} = 1.65 V$ | | - | 0.5 | 1.2 | - | 1.3 | Ω |
| | | $V_{CC} = 2.3 V$ | | - | 0.15 | 0.3 | - | 0.35 | Ω |
| | | $V_{CC} = 2.7 V$ | | - | 0.13 | 0.3 | - | 0.35 | Ω |
| | | $V_{CC} = 4.3 V$ | | - | 0.2 | 0.4 | - | 0.45 | Ω |

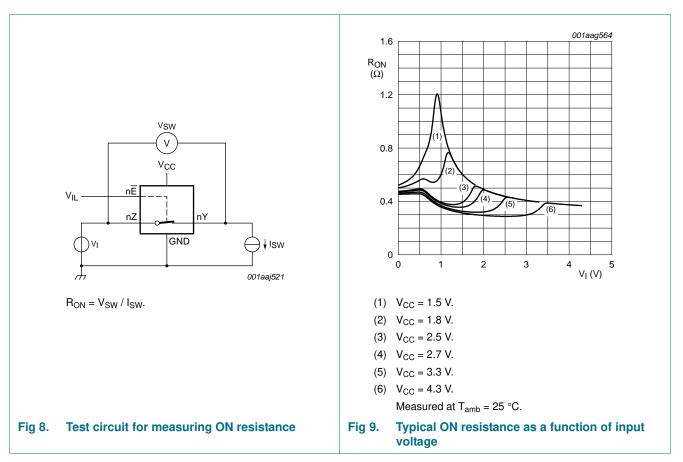
[1] Typical values are measured at $T_{amb} = 25 \ ^{\circ}C$.

[2] Measured at identical V_{CC} , temperature and input voltage.

NX3L2T384

Dual low-ohmic single-pole single-throw analog switch

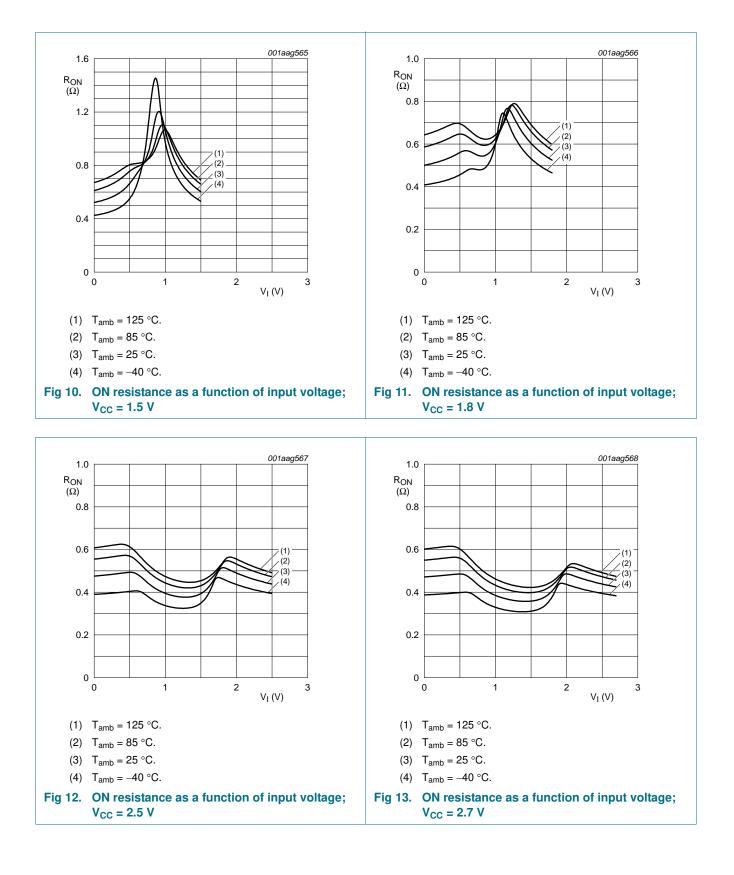
[3] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V_{CC} and temperature.



11.3 ON resistance test circuit and graphs

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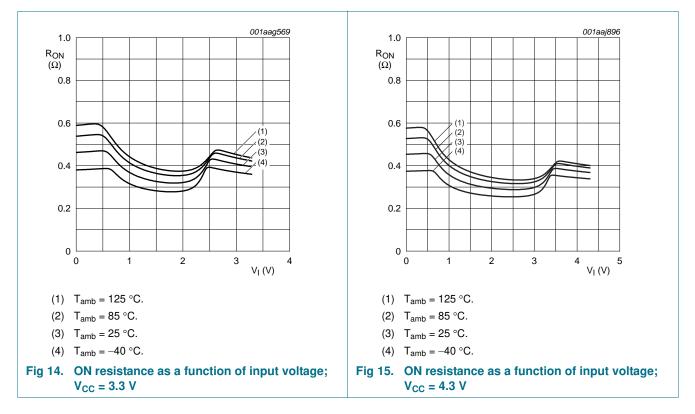
Dual low-ohmic single-pole single-throw analog switch



8 of 20

NX3L2T384

Dual low-ohmic single-pole single-throw analog switch



12. Dynamic characteristics

Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 17.

| Symbol | Parameter | Conditions | | _{mb} = 25 | °C | T _{amb} = | Unit | | |
|------------------|--------------|--|-----|----------------------|-----|--------------------|----------------|-----------------|----|
| | | | Min | Typ <mark>[1]</mark> | Мах | Min | Мах (85 °С) | Max (125 °C) | |
| t _{en} | enable time | nĒ to nZ or nY; see <u>Figure 16</u> | | | | | | | |
| | | $V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$ | - | 50 | 90 | - | 120 | 120 | ns |
| | | V _{CC} = 1.65 V to 1.95 V | - | 36 | 70 | - | 80 | 90 | ns |
| | | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ | - | 24 | 45 | - | 50 | 55 | ns |
| | | $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$ | - | 22 | 40 | - | 45 | 50 | ns |
| | | V_{CC} = 3.6 V to 4.3 V | - | 22 | 40 | - | 45 | 50 | ns |
| t _{dis} | disable time | nĒ to nZ or nY; see <u>Figure 16</u> | | | | | | | |
| | | $V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$ | - | 30 | 45 | - | 50 | 60 | ns |
| | | V _{CC} = 1.65 V to 1.95 V | - | 20 | 30 | - | 35 | 40 | ns |
| | | $V_{CC} = 2.3 \text{ V} \text{ to } 2.7 \text{ V}$ | - | 15 | 20 | - | 22 | 25 | ns |
| | | $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$ | - | 11 | 15 | - | 18 | 22 | ns |
| | | $V_{CC} = 3.6 V \text{ to } 4.3 V$ | - | 11 | 15 | - | 18 | 22 | ns |

[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.5 V, 1.8 V, 2.5 V, 3.3 V and 4.3 V respectively.

Dual low-ohmic single-pole single-throw analog switch

12.1 Waveform and test circuits

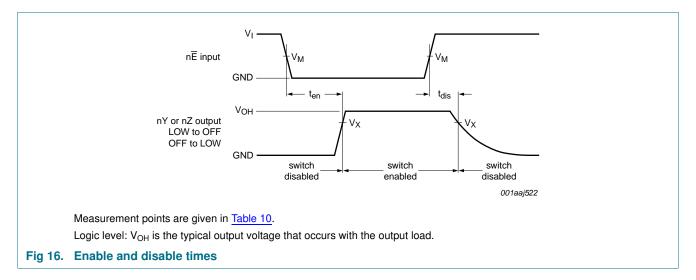


Table 10.Measurement points

| Supply voltage | Input | Output |
|-----------------|--------------------|--------------------|
| V _{CC} | V _M | V _X |
| 1.4 V to 4.3 V | 0.5V _{CC} | 0.9V _{OH} |

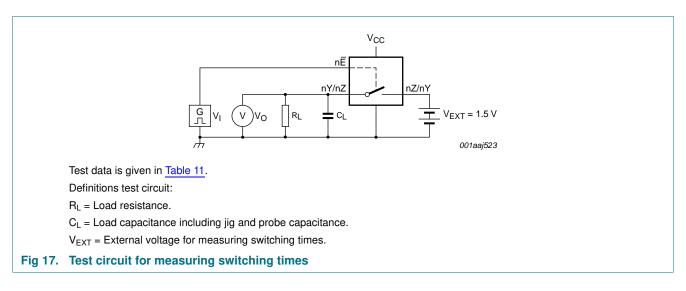


Table 11. Test data

| Supply voltage | Input | | Load | | |
|-----------------|-----------------|---------------------------------|-------|------|--|
| V _{cc} | VI | t _r , t _f | CL | RL | |
| 1.4 V to 4.3 V | V _{CC} | \leq 2.5 ns | 35 pF | 50 Ω | |

NX3L2T384 Product data sheet

Dual low-ohmic single-pole single-throw analog switch

12.2 Additional dynamic characteristics

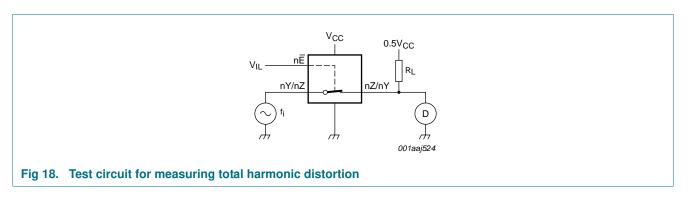
Table 12. Additional dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); $V_I = GND$ or V_{CC} (unless otherwise specified); $t_r = t_f \le 2.5$ ns.

| Symbol | Parameter | Conditions | | T _{amb} = 25 °C | | | Unit |
|---|---|---|-----|--------------------------|------|-----|------|
| | | | | Min | Тур | Max | |
| THD total harmonic distortion | | f_i = 20 Hz to 20 kHz; R_L = 32 Ω ; see <u>Figure 18</u> | [1] | | | | |
| | distortion | V _{CC} = 1.4 V; V _I = 1 V (p-p) | | - | 0.15 | - | % |
| | | V _{CC} = 1.65 V; V _I = 1.2 V (p-p) | | - | 0.10 | - | % |
| | | V _{CC} = 2.3 V; V _I = 1.5 V (p-p) | | - | 0.02 | - | % |
| | | V _{CC} = 2.7 V; V _I = 2 V (p-p) | | - | 0.02 | - | % |
| | $V_{CC} = 4.3 \text{ V}; \text{ V}_{I} = 2 \text{ V} (p-p)$ | | - | 0.02 | - | % | |
| f _(-3dB) -3 dB frequency response | $R_L = 50 \Omega$; see Figure 19 | [1] | | | | | |
| | response | $V_{CC} = 1.4 \text{ V} \text{ to } 4.3 \text{ V}$ | | - | 60 | - | MHz |
| α_{iso} | isolation (OFF-state) | $f_i = 100 \text{ kHz}; \text{ R}_L = 50 \Omega; \text{ see } \frac{\text{Figure 20}}{100 \text{ kHz}}$ | [1] | | | | |
| | | $V_{CC} = 1.4 \text{ V} \text{ to } 4.3 \text{ V}$ | | - | -90 | - | dB |
| V _{ct} crosstalk voltage | crosstalk voltage | between digital inputs and switch; $f_i = 1 \text{ MHz}$; $C_L = 50 \text{ pF}$; $R_L = 50 \Omega$; see Figure 21 | | | | | |
| | V _{CC} = 1.4 V to 3.6 V | | - | 0.2 | - | V | |
| | V _{CC} = 3.6 V to 4.3 V | | - | 0.2 | - | V | |
| Xtalk crosstalk | between switches; $f_i = 100 \text{ kHz}$; $R_L = 50 \Omega$; see <u>Figure 22</u> | <u>[1]</u> | | | | | |
| | V _{CC} = 1.4 V to 4.3 V | | - | -90 | - | dB | |
| Q _{inj} charge | charge injection | $ f_i = 1 \text{ MHz}; C_L = 0.1 \text{ nF}; R_L = 1 \text{ M}\Omega; V_{gen} = 0 \text{ V}; \\ R_{gen} = 0 \Omega; \text{ see } \frac{\text{Figure 23}}{2} $ | | | | | |
| | | $V_{CC} = 1.5 V$ | | - | 3 | - | рС |
| | | $V_{CC} = 1.8 V$ | | - | 3 | - | рС |
| | | $V_{CC} = 2.5 V$ | | - | 3 | - | рС |
| | | $V_{CC} = 3.3 V$ | | - | 3 | - | рС |
| | | $V_{CC} = 4.3 V$ | | - | 6 | - | рС |

[1] f_i is biased at 0.5V_{CC}.

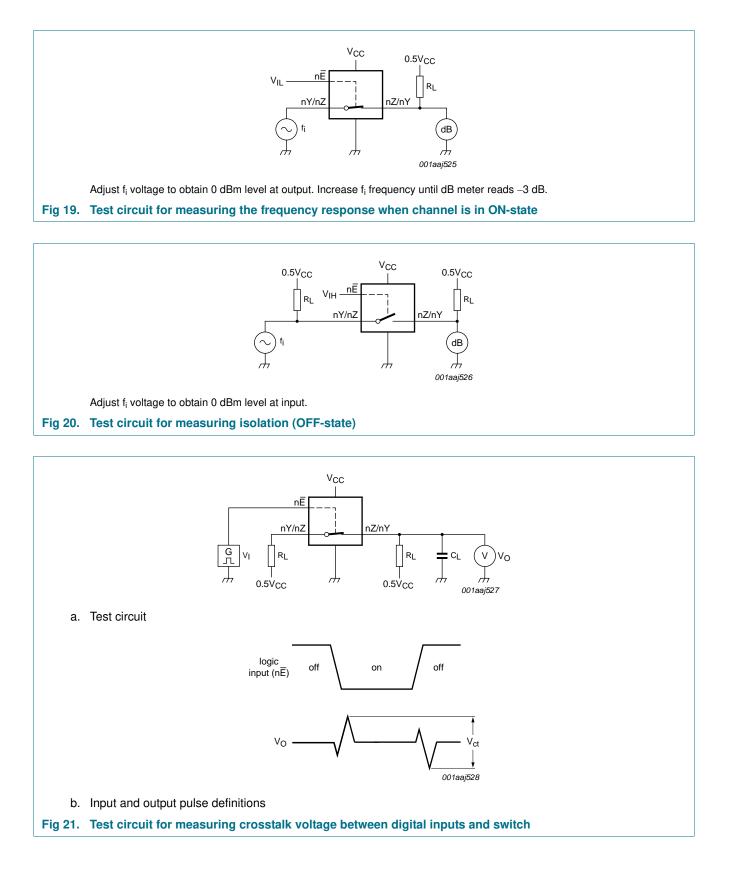
13. Test circuits



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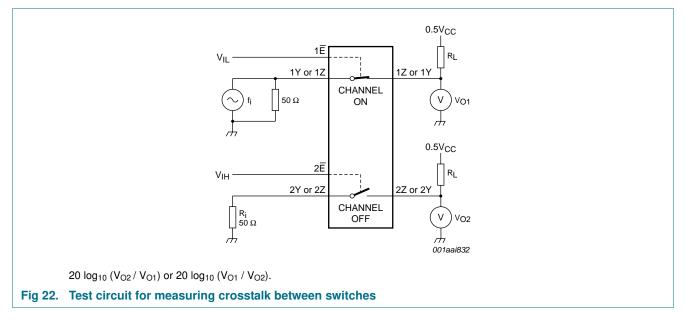
Dual low-ohmic single-pole single-throw analog switch

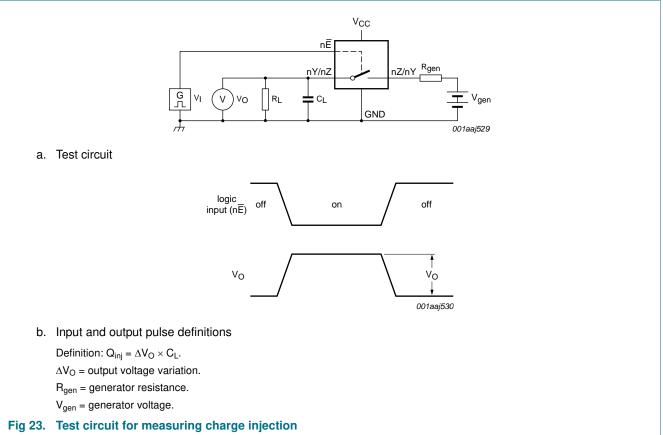


12 of 20

NX3L2T384

Dual low-ohmic single-pole single-throw analog switch





Dual low-ohmic single-pole single-throw analog switch

14. Package outline

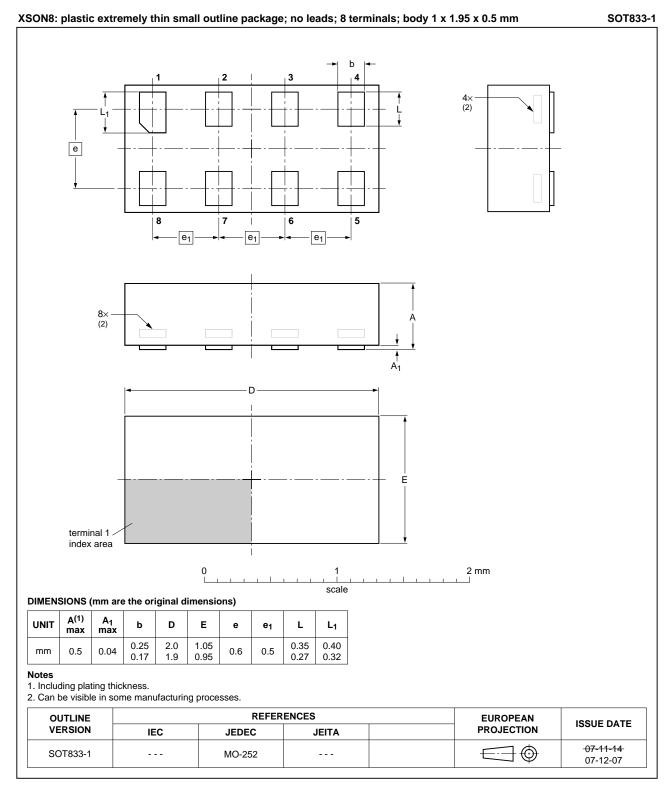
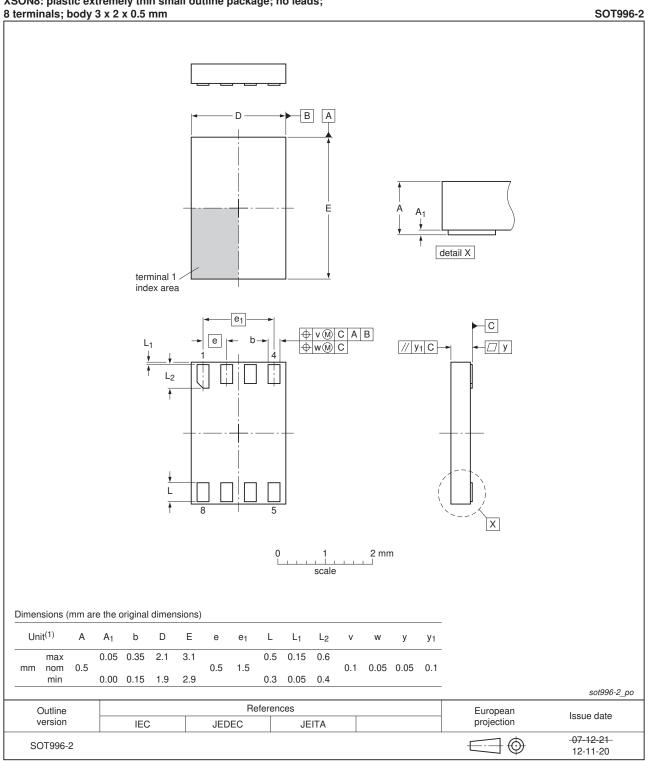


Fig 24. Package outline SOT833-1 (XSON8)

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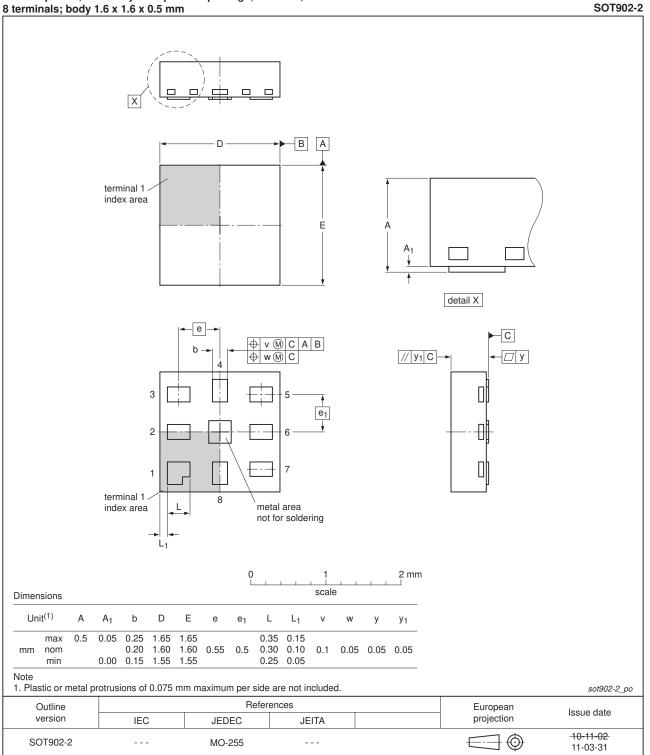


XSON8: plastic extremely thin small outline package; no leads;

Fig 25. Package outline SOT996-2 (XSON8)

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Dual low-ohmic single-pole single-throw analog switch



XQFN8: plastic, extremely thin quad flat package; no leads; 8 terminals: body 1.6 x 1.6 x 0.5 mm

Fig 26. Package outline SOT902-2 (XQFN8)

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Dual low-ohmic single-pole single-throw analog switch

15. Abbreviations

| Acronym CDM | Description Charged Device Model |
|----------------|---|
| | - |
| | |
| CMOS | Complementary Metal Oxide Semiconductor |
| ESD | ElectroStatic Discharge |
| HBM | Human Body Model |
| MM | Machine Model |

16. Revision history

Table 14.Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|----------------|----------------------------------|-------------------------|---------------------|---------------|
| NX3L2T384 v.5 | 20130208 | Product data sheet | - | NX3L2T384 v.4 |
| Modifications: | For type nun | nber NX3L2T384GD XSON8U | has changed to XSON | N8. |
| NX3L2T384 v.4 | 20120621 | Product data sheet | - | NX3L2T384 v.3 |
| NX3L2T384 v.3 | 20111107 | Product data sheet | - | NX3L2T384 v.2 |
| NX3L2T384 v.2 | 20101221 | Product data sheet | - | NX3L2T384 v.1 |
| NX3L2T384 v.1 | 20091022 | Product data sheet | - | - |

17. Legal information

17.1 Data sheet status

| Document status[1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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NX3L2T384

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19. Contents

| 1 | General description | 1 |
|--------------|---------------------------------------|---|
| 2 | Features and benefits | 1 |
| 3 | Applications | 2 |
| 4 | Ordering information | 2 |
| 5 | Marking | 2 |
| 6 | Functional diagram | 2 |
| 7 | Pinning information | 3 |
| 7.1 | Pinning | 3 |
| 7.2 | Pin description | 3 |
| 8 | Functional description | 4 |
| 9 | Limiting values | 4 |
| 10 | Recommended operating conditions | 4 |
| 11 | Static characteristics | 5 |
| 11.1 | Test circuits | 6 |
| 11.2 | | 6 |
| 11.3 | ON resistance test circuit and graphs | 7 |
| 12 | Dynamic characteristics | |
| 12.1 | Waveform and test circuits 1 | - |
| 12.2 | Additional dynamic characteristics 1 | |
| 13 | Test circuits 1 | - |
| 14 | Package outline 1 | 4 |
| 15 | Abbreviations 1 | 7 |
| 16 | | 7 |
| 17 | Legal information 1 | 8 |
| 17.1 | | 8 |
| 17.2 | Definitions 1 | |
| 17.3 17.4 | Disclaimers | - |
| | | 9 |
| 18 | Contact information 1 | - |
| 19 | Contents 2 | 0 |

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Date of release: 8 February 2013 Document identifier: NX3L2T384